

10/127,692

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	14	(("5498554") or ("6258701") or ("6686233") or ("6713347") or ("6207510") or ("5933731") or ("6099652")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/07 15:04
S1	4537	((257/347) or (257/350) or (257/352) or (257/371) or (257/415)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/07 15:03
S18	6	(("5242841") or ("5844264") or ("6580138")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/06 16:11
S19	1922	photodiode and (mems microelectromechanical electromechanical micromechanical) and @ad<"20020222"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:13
S20	0	S19 and substrate and circuit and ((high adj voltage) near4 well) and ((low adj voltage) near4 well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:14
S21	0	S19 and ((high adj voltage) near4 well) and ((low adj voltage) near4 well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:22
S22	1660	S19 and well	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:14
S23	38	S19 and (high near5 well) and (low near5 well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:15
S24	465	((high adj voltage) near4 well) and ((low adj voltage) near4 well)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:40

S25	15	S24 and photodiode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:23
S26	12	S25 and @ad<"20020222"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:23
S27	680	((high adj voltage) near4 (p n)) and ((low adj voltage) near4 (p n)) and @ad<"20020222"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:41
S28	2	S27 and photodiode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:49
S29	649	(257/371).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/04/06 16:49
S30	556	S29 and @ad<"20020222"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 16:49
S31	4	S30 and photodiode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 17:04
S32	702	photodiode and (mems microelectromechanical micromechanical electromechanical) and @ad<"20020222" and substrate and circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 17:06
S33	98	(photodiode and (mems microelectromechanical micromechanical electromechanical) near9 substrate) and @ad<"20020222" and circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 17:08
S34	9	((photodiode and (mems microelectromechanical micromechanical electromechanical)) near9 substrate) and @ad<"20020222" and circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 17:08

S35	13	((photodiode and (mems microelectromechanical micromechanical electromechanical)) near9 substrate) and @ad<"20020222"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/06 17:08
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